

ADJUSTABLE PRECISION SHUNT REGULATORS

AN431

Pin Configuration

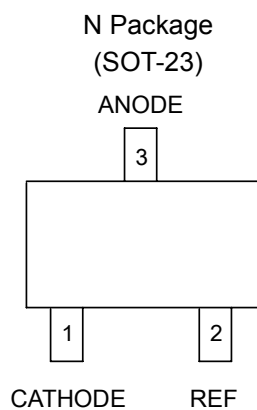


Figure 2. Pin Configuration of AN431 (Top View)

Functional Block Diagram

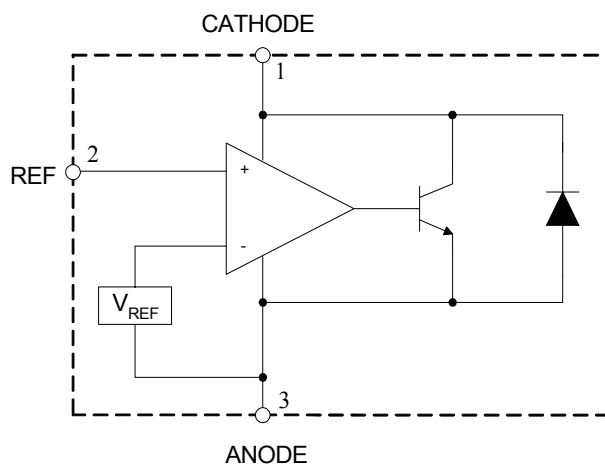
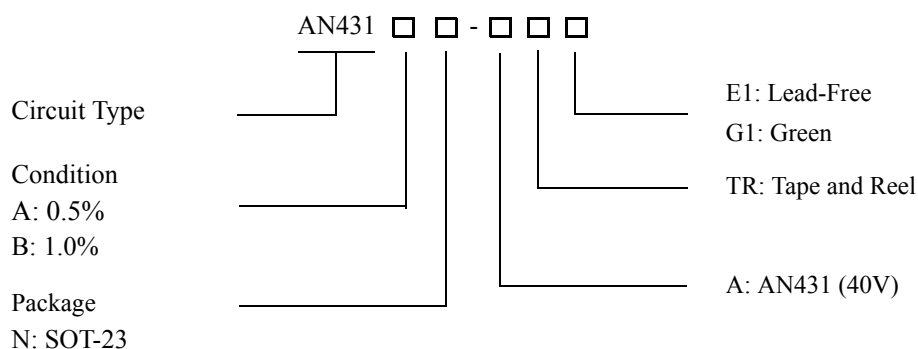


Figure 3. Functional Block Diagram of AN431

**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Ordering Information**

Package	Temperature Range	Condition	Part Number		Marking ID		Packing Type
			Lead Free	Green	Lead Free	Green	
SOT-23	-40 to 125°C	0.5%	AN431AN-ATRE1	AN431AN-ATRG1	EB1	GB1	Tape & Reel
		1.0%	AN431BN-ATRE1	AN431BN-ATRG1	EB2	GB2	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Cathode Voltage	V_{KA}	40	V
Cathode Current Range (Continuous)	I_{KA}	-100 to 150	mA
Reference Input Current Range	I_{REF}	10	mA
Power Dissipation	P_D	370	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-65 to 150	°C
ESD (Human Body Model)	ESD	2000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Cathode Voltage	V_{KA}	V_{REF}	36	V
Cathode Current	I_{KA}	1.0	100	mA
Operating Ambient Temperature Range		-40	125	°C



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Electrical Characteristics

Operating Conditions: $T_A=25^{\circ}\text{C}$, unless otherwise specified.

Parameter	Test Circuit	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	0.5%	V_{REF}	$V_{\text{KA}}=V_{\text{REF}}, I_{\text{KA}}=10\text{mA}$	2.487	2.500	2.512	V
	1.0%			2.475	2.500	2.525	
Deviation of Reference Voltage Over Full Temperature Range	4	ΔV_{REF}	$V_{\text{KA}}=V_{\text{REF}}, I_{\text{KA}}=10\text{mA}$	0 to 70°C	4.5	8	mV
				-40 to 85°C	4.5	10	
				-40 to 125°C	4.5	16	
Ratio of Change in Reference Voltage to the Change in Cathode Voltage	5	$\frac{\Delta V_{\text{REF}}}{\Delta V_{\text{KA}}}$	$I_{\text{KA}}=10\text{mA}$	$\Delta V_{\text{KA}}=10\text{V to } V_{\text{REF}}$	-1.0	-2.7	mV/V
				$\Delta V_{\text{KA}}=36\text{V to } 10\text{V}$	-0.5	-2.0	
Reference Current	5	I_{REF}	$I_{\text{KA}}=10\text{mA}, R1=10\text{K}\Omega, R2=\infty$		0.7	4	μA
Deviation of Reference Current Over Full Temperature Range	5	ΔI_{REF}	$I_{\text{KA}}=10\text{mA}, R1=10\text{K}\Omega, R2=\infty, T_A=-40 \text{ to } 125^{\circ}\text{C}$		0.4	1.2	μA
Minimum Cathode Current for Regulation	4	$I_{\text{KA}}(\text{Min})$	$V_{\text{KA}}=V_{\text{REF}}$		0.4	1.0	mA
Off-state Cathode Current	6	$I_{\text{KA}}(\text{Off})$	$V_{\text{KA}}=36\text{V}, V_{\text{REF}}=0$		0.05	1.0	μA
Dynamic Impedance	4	Z_{KA}	$V_{\text{KA}}=V_{\text{REF}}, I_{\text{KA}}=1 \text{ to } 100\text{mA}, f \leq 1.0\text{kHz}$		0.15	0.5	Ω
Thermal Resistance		θ_{JC}	SOT-23		135		$^{\circ}\text{C/W}$

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Electrical Characteristics (Continued)

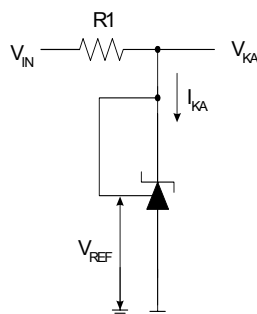


Figure 4. Test Circuit 4 for $V_{KA} = V_{REF}$

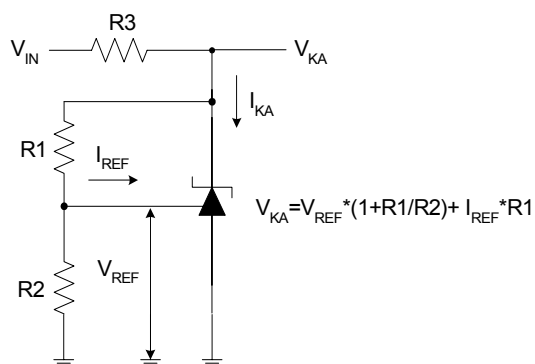


Figure 5. Test Circuit 5 for $V_{KA} > V_{REF}$

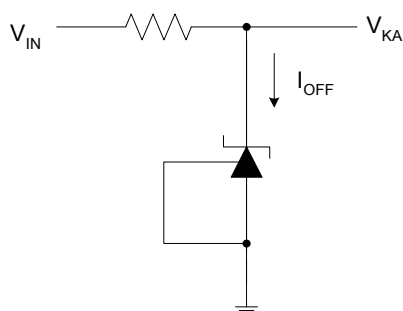


Figure 6. Test Circuit 6 for I_{OFF}

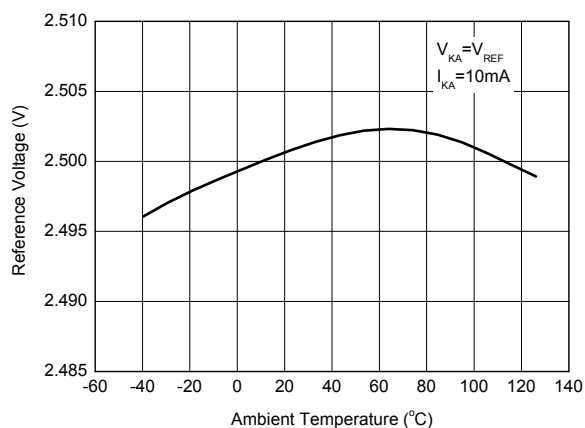
**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Typical Performance Characteristics**

Figure 7. Reference Voltage vs. Ambient Temperature

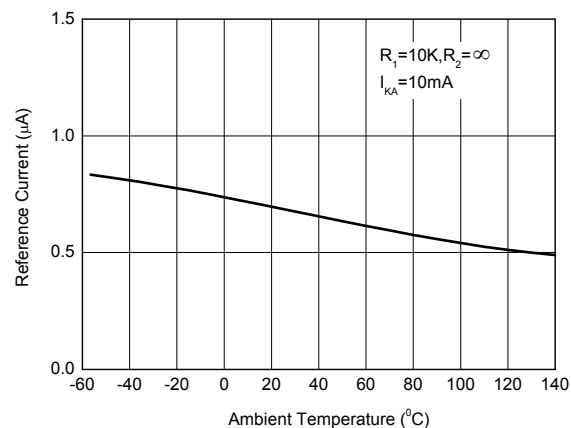


Figure 8. Reference Current vs. Ambient Temperature

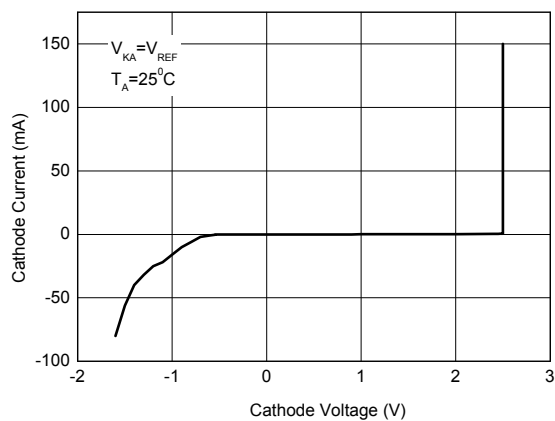


Figure 9. Cathode Current vs. Cathode Voltage

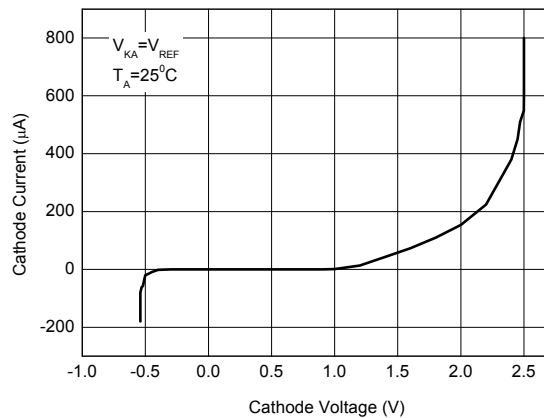


Figure 10. Cathode Current vs. Cathode Voltage

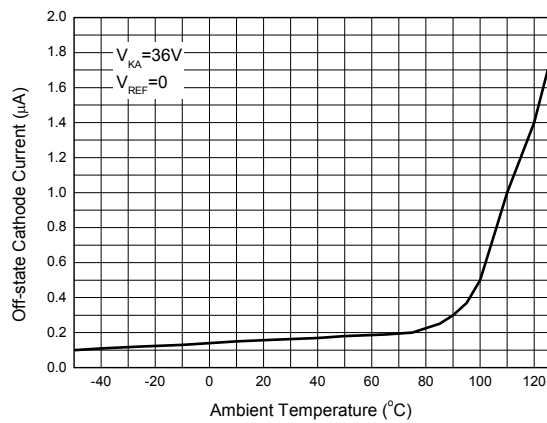
**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Typical Performance Characteristics (Continued)**

Figure 11. Off-state Cathode Current vs. Ambient Temperature

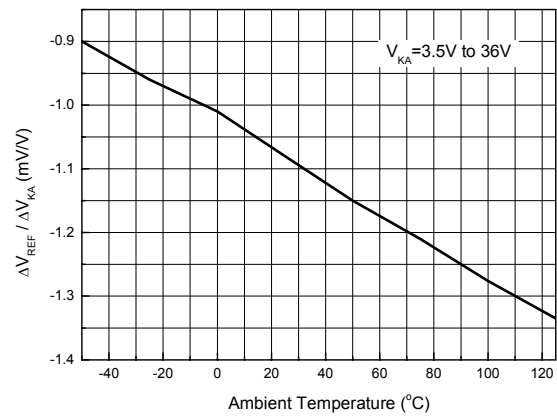


Figure 12. Ratio of Delta Reference Voltage to the Ratio of Delta Cathode Voltage

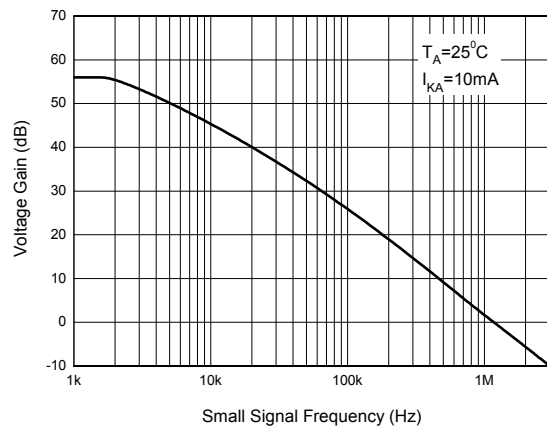
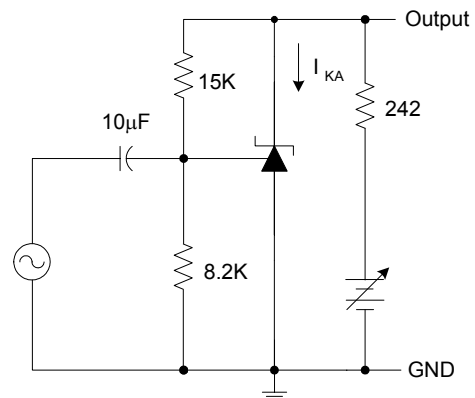


Figure 13. Small Signal Voltage Gain vs. Frequency



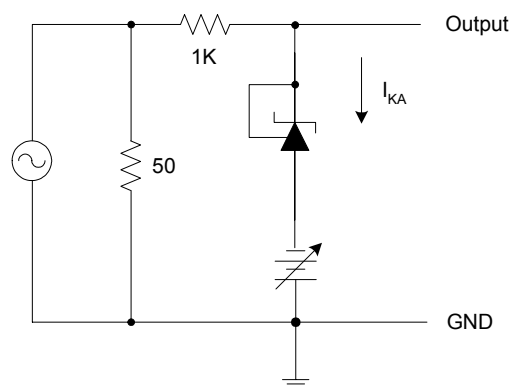
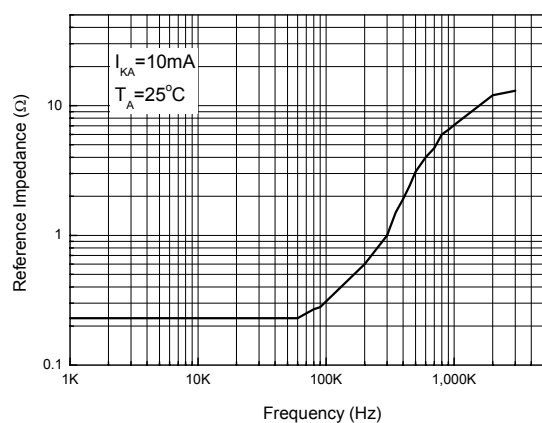
**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Typical Performance Characteristics (Continued)**

Figure 14. Reference Impedance vs. Frequency

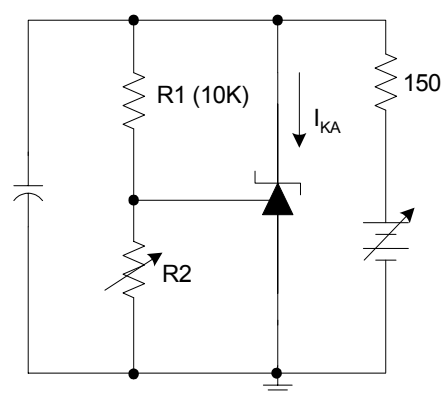
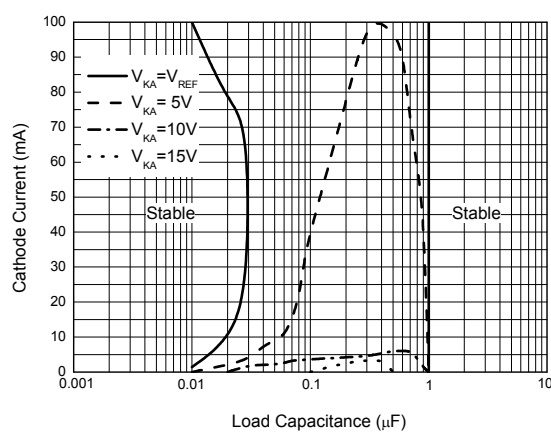


Figure 15. Stability Boundary Conditions vs. Load Capacitance

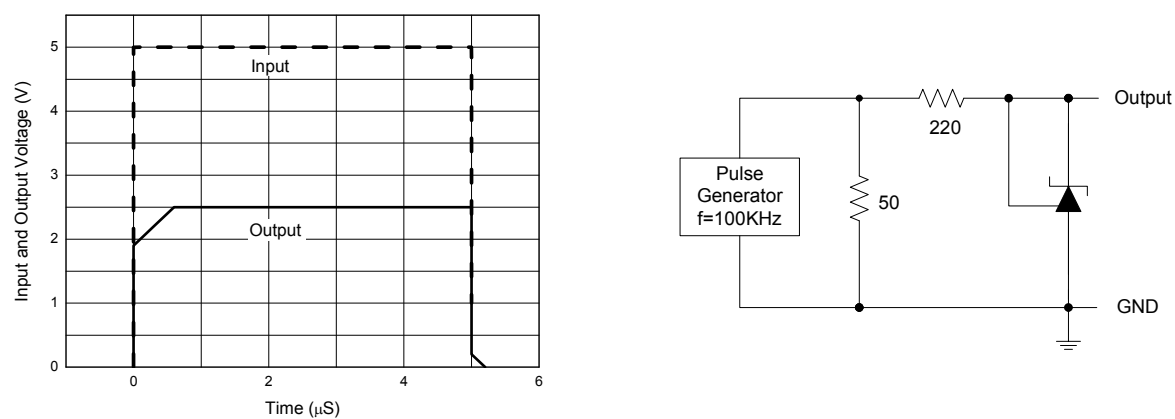
**ADJUSTABLE PRECISION SHUNT REGULATORS****AN431****Typical Performance Characteristics (Continued)**

Figure 16. Pulse Response of Input and Output Voltage

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Typical Application

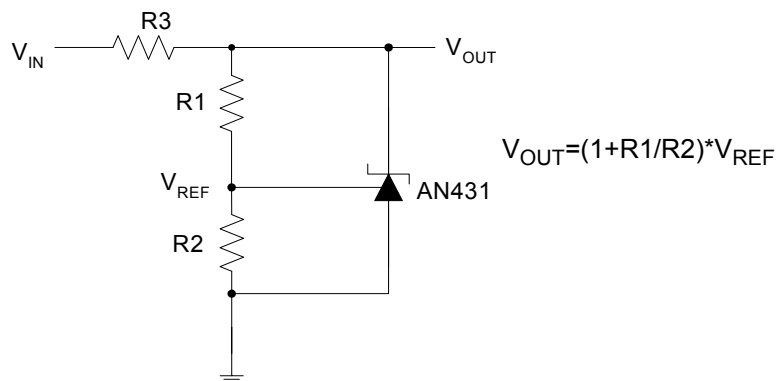


Figure 17. Shunt Regulator

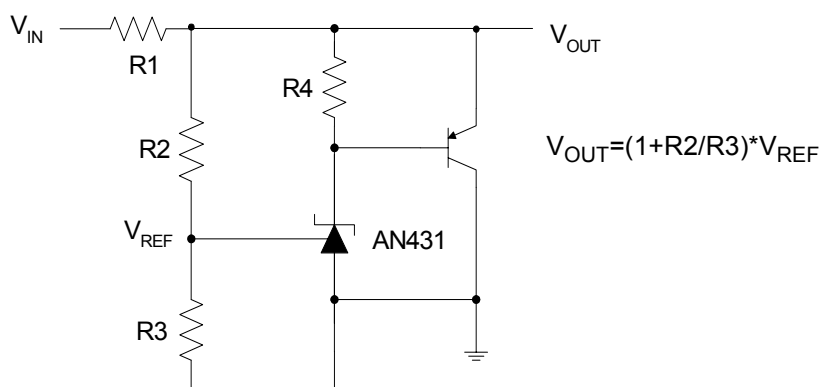


Figure 18. High Current Shunt Regulator

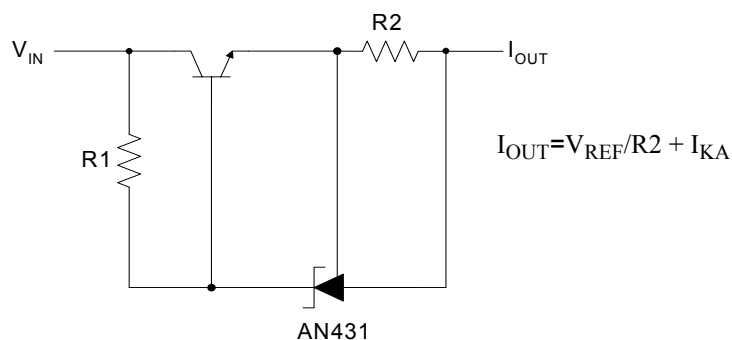


Figure 19. Current Source or Current Limit

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Typical Application (Continued)

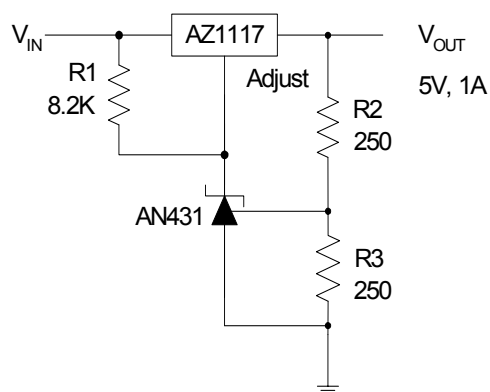


Figure 20. Precision 5V 1A Regulator

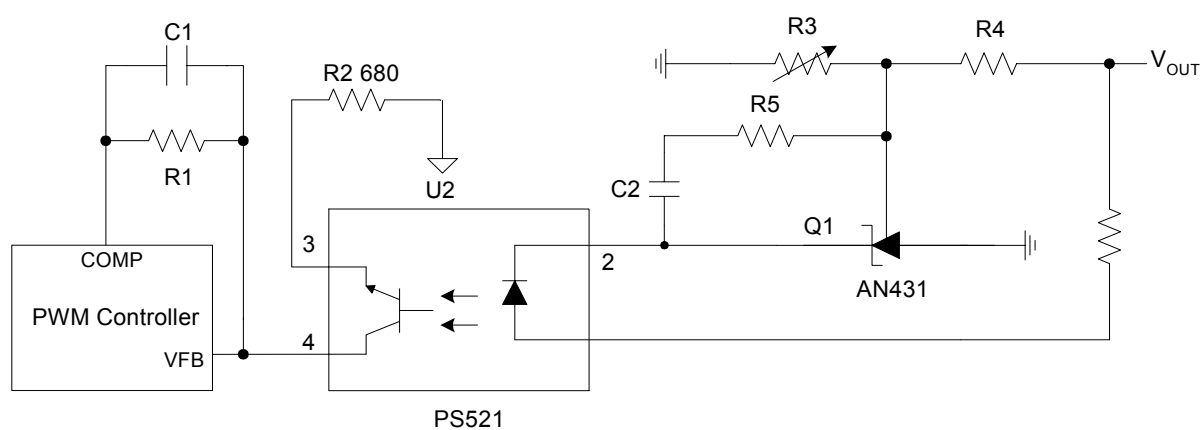


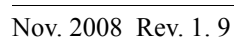
Figure 21. PWM Converter with Reference



AN431

SOT-23

Unit: mm(inch)



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MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China
Tel: +86-21-24162266, Fax: +86-21-24162277

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, China
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office
Room E, 5F, Noble Center, No.1006, 3rd Fuzhong Road, Futian District, Shenzhen, 518026, China
Tel: +86-755-8826 7951
Fax: +86-755-8826 7865

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited
4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan
Tel: +886-2-2656 2808
Fax: +886-2-2656 2806

USA Office

BCD Semiconductor Corp.
30920 Huntwood Ave. Hayward, CA 94544, USA
Tel : +1-510-324-2988
Fax: +1-510-324-2788